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High-speed switching diodes

Rev. 6 — 24 September 2014

**Product data sheet** 

### 1. Product profile

### 1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number	Package			Configuration	Package	
	NXP	JEITA	JEDEC	-	configuration	
BAS16	SOT23	-	TO-236AB	single	small	
BAS16H	SOD123F	-	-	single	small and flat lead	
BAS16J	SOD323F	SC-90	-	single	very small and flat lead	
BAS16L	SOD882	-	-	single	leadless ultra small	
BAS16T	SOT416	SC-75	-	single	ultra small	
BAS16VV	SOT666	-	-	triple isolated	ultra small and flat lead	
BAS16VY	SOT363	SC-88	-	triple isolated	very small	
BAS16W	SOT323	SC-70	-	single	very small	
BAS316	SOD323	SC-76	-	single	very small	
BAS516	SOD523	SC-79	-	single	ultra small and flat lead	

#### 1.2 Features and benefits

- High switching speed:  $t_{rr} \le 4$  ns
- Low leakage current
- Repetitive peak reverse voltage: V<sub>RRM</sub> ≤ 100 V
- AEC-Q101 qualified

### **1.3 Applications**

- High-speed switching
- General-purpose switching

- Low capacitance
- Reverse voltage:  $V_R \le 100 \text{ V}$
- Small SMD plastic packages



### 1.4 Quick reference data

#### Table 2. Quick reference data

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
V <sub>R</sub>	reverse voltage			-	-	100	V	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 80 V		-	-	0.5	μA	
t <sub>rr</sub>	reverse recovery time	$    I_F = 10 \text{ mA}; \  I_R = 10 \text{ mA}; \\     R_L = 100 \ \Omega; \  I_{R(meas)} = 1 \text{ mA} $		-	-	4	ns	

### 2. Pinning information

Table 3. Pir	nning			
Pin	Description		Simplified outline	Graphic symbol
BAS16; BAS1	6T; BAS16W			
1	anode			0
2	not connected		3	
3	cathode		2	1 <u>             </u> 2 006aaa764
BAS16H; BAS	S16J; BAS316; BAS516			
1	cathode	[1]		
2	anode		1 2 001aab540	1 2 006aab040
BAS16L				
1	cathode	[1]		
2	anode		1   2     Transparent top view	1 2 006aab040
BAS16VV; BA	S16VY			
1	anode (diode 1)			
2	anode (diode 2)			
3	anode (diode 3)			
4	cathode (diode 3)			
5	cathode (diode 2)			
6	cathode (diode 1)		001aab555	1 2 3 <i>006aab106</i>

[1] The marking bar indicates the cathode.

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High-speed switching diodes

### 3. Ordering information

Table 4.	Ordering	information
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Type number	Package						
	Name	Description	Version				
BAS16	TO-236AB	plastic surface-mounted package; 3 leads	SOT23				
BAS16H	-	plastic surface-mounted package; 2 leads	SOD123F				
BAS16J	SC-90	plastic surface-mounted package; 2 leads	SOD323F				
BAS16L	DFN1006-2	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882				
BAS16T	SC-75	plastic surface-mounted package; 3 leads	SOT416				
BAS16VV	-	plastic surface-mounted package; 6 leads	SOT666				
BAS16VY	SC-88	plastic surface-mounted package; 6 leads	SOT363				
BAS16W	SC-70	plastic surface-mounted package; 3 leads	SOT323				
BAS316	SC-76	plastic surface-mounted package; 2 leads	SOD323				
BAS516	SC-79	plastic surface-mounted package; 2 leads	SOD523				

### 4. Marking

Table 5.   Marking codes	
Type number	Marking code <sup>[1]</sup>
BAS16	A6*
BAS16H	A1
BAS16J	AR
BAS16L	S2
BAS16T	A6
BAS16VV	53
BAS16VY	16*
BAS16W	A6*
BAS316	A6
BAS516	6

[1] \* = placeholder for manufacturing site code

### 5. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V <sub>RRM</sub>	repetitive peak reverse voltage		-	100	V
V <sub>R</sub>	reverse voltage		-	100	V

High-speed switching diodes

Symbol	Parameter	Conditions		Min	Max	Unit
l <sub>F</sub>	forward current					
	BAS16		[1]	-	215	mA
	BAS16H BAS16L		[2]	-	215	mA
	BAS16T		<u>[1]</u>	-	155	mA
	BAS16VV BAS16VY		<u>[1][3]</u>	-	200	mA
	BAS16W		[1]	-	175	mA
	BAS16J BAS316 BAS516		[1]	-	250	mA
I <sub>FRM</sub>	repetitive peak forward current	$\begin{array}{l} t_p \leq 0.5 \text{ ms}; \\ \delta \leq 0.25 \end{array}$		-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j(init)</sub> = 25 °C				
		t <sub>p</sub> = 1 μs		-	4	А
		t <sub>p</sub> = 1 ms		-	1	А
		t <sub>p</sub> = 1 s		-	0.5	А
P <sub>tot</sub>	total power dissipation					
	BAS16	$T_{amb} \le 25 \ ^{\circ}C$	[1]	-	250	mW
	BAS16H	$T_{amb} \le 25 \ ^{\circ}C$	[2]	-	380	mW
			[5]	-	830	mW
	BAS16J	$T_{amb} \le 25 \ ^{\circ}C$	[5]	-	550	mW
	BAS16L	$T_{amb} \le 25 \ ^{\circ}C$	[2]	-	250	mW
	BAS16T	$T_{sp} \le 90 \ ^{\circ}C$	<u>[1][4]</u>	-	170	mW
	BAS16VV	$T_{amb} \le 25 \ ^{\circ}C$	[1][3]	-	180	mW
	BAS16VY	$T_{sp} \le 85 \ ^{\circ}C$	[1][3][6]	-	250	mW
	BAS16W	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u>	-	200	mW
	BAS316	$T_{sp} \le 90 \ ^{\circ}C$	<u>[1][4]</u>	-	400	mW
	BAS516	$T_{sp} \le 90 \ ^{\circ}C$	<u>[1][4]</u>	-	500	mW
Per device						
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	+150	°C
T <sub>stq</sub>	storage temperature			-65	+150	°C

#### Table 6. Limiting values ...continued

accordance with the Absolute Maximum Rating System (IEC 60134).

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

- [2] Device mounted on an FR4 PCB with 60  $\mu$ m copper strip line.
- [3] Single diode loaded.
- [4] Soldering point of cathode tab.
- [5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [6] Soldering points at pins 4, 5 and 6.

High-speed switching diodes

### 6. Thermal characteristics

Table 7.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air					
	BAS16		[1]	-	-	500	K/W
	BAS16H		[2]	-	-	330	K/W
			[3]	-	-	150	K/W
	BAS16J		[3]	-	-	230	K/W
	BAS16L		[2]	-	-	500	K/W
	BAS16VV		[2][4]	-	-	700	K/W
			[3][4]	-	-	410	K/W
	BAS16W		[1]	-	-	625	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point						
	BAS16			-	-	330	K/W
	BAS16H		[5]	-	-	70	K/W
	BAS16J		[5]	-	-	55	K/W
	BAS16T			-	-	350	K/W
	BAS16VY		[4][6]	-	-	260	K/W
	BAS16W			-	-	300	K/W
	BAS316		[5]	-	-	150	K/W
	BAS516		[5]	-	-	120	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB with 60  $\mu m$  copper strip line.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[4] Single diode loaded.

[5] Soldering point of cathode tab.

[6] Soldering points at pins 4, 5 and 6.

### 7. Characteristics

1 <sub>amb</sub> = 25	<i>I<sub>amb</sub> = 25 °C unless otherwise specified.</i>								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Per diode	9								
V <sub>F</sub>	forward voltage		[1]						
		I <sub>F</sub> = 1 mA		-	-	715	mV		
		I <sub>F</sub> = 10 mA		-	-	855	mV		
		I <sub>F</sub> = 50 mA		-	-	1	V		
		I <sub>F</sub> = 150 mA		-	-	1.25	V		
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V		-	-	30	nA		
		V <sub>R</sub> = 80 V		-	-	0.5	μ <b>A</b>		
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C		-	-	30	μ <b>A</b>		
		V <sub>R</sub> = 80 V; T <sub>j</sub> = 150 °C		-	-	50	μ <b>A</b>		
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V							
	BAS16; BAS16H; BAS16J; BAS16L; BAS16T; BAS16VV; BAS16VY; BAS16W; BAS316			-	-	1.5	pF		
	BAS516			-	-	1	pF		
t <sub>rr</sub>	reverse recovery time	$     I_F = 10 \text{ mA}; I_R = 10 \text{ mA};      R_L = 100 \Omega;      I_{R(meas)} = 1 \text{ mA}                                   $		-	-	4	ns		
V <sub>FR</sub>	forward recovery voltage	$I_F = 10 \text{ mA}; t_r = 20 \text{ ns}$		-	-	1.75	V		

#### Table 8.Characteristics

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

#### **NXP Semiconductors**

### **BAS16 series**



High-speed switching diodes

### 8. Test information



#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

**High-speed switching diodes** 

#### **Package outline** 9.



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### **NXP Semiconductors**

# **BAS16 series**



High-speed switching diodes

### 10. Soldering







**High-speed switching diodes** 



BAS16\_SER **Product data sheet** 

High-speed switching diodes



BAS16\_SER Product data sheet





High-speed switching diodes

### 11. Revision history

Table 9.	<b>Revision histo</b>	ry		
Document	ID	Release date		

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS16_SER_6	20140924	Product data sheet	-	BAS16_SER_5
Modifications:	Section 1.2 "F	eatures and benefits": update	d	<u>.</u>
	Section 4 "Ma	urking": updated		
	Table 6 "Limit	ing values": updated		
	Section 8 "Tes	st information": updated		
	Section 12 "Le	egal information": updated		
BAS16_SER_5	20080825	Product data sheet	-	BAS16_4 BAS16H_1 BAS16J_1 BAS16L_1 BAS16T_1 BAS16VV_BAS16VY_3 BAS16W_4 BAS316_4 BAS516_1
BAS16_4	20011010	Product specification	-	BAS16_3
BAS16H_1	20050415	Product data sheet	-	-
BAS16J_1	20070308	Product data sheet	-	-
BAS16L_1	20030623	Product specification	-	-
BAS16T_1	19980120	Product specification	-	-
BAS16VV_BAS16VY_3	20070420	Product data sheet	-	BAS16VV_BAS16VY_2
BAS16W_4	19990506	Product specification	-	BAS16W_3
BAS316_4	20040204	Product specification	-	BAS316_3
BAS516_1	19980831	Product specification	-	-

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### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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#### High-speed switching diodes

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